

SOFT-LITHOGRAPHY

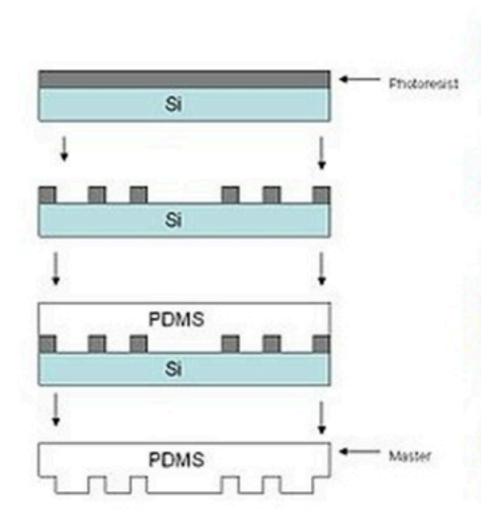
G. Vozzi







+ Soft-lithography



Soft-lithography

Micro-stamping

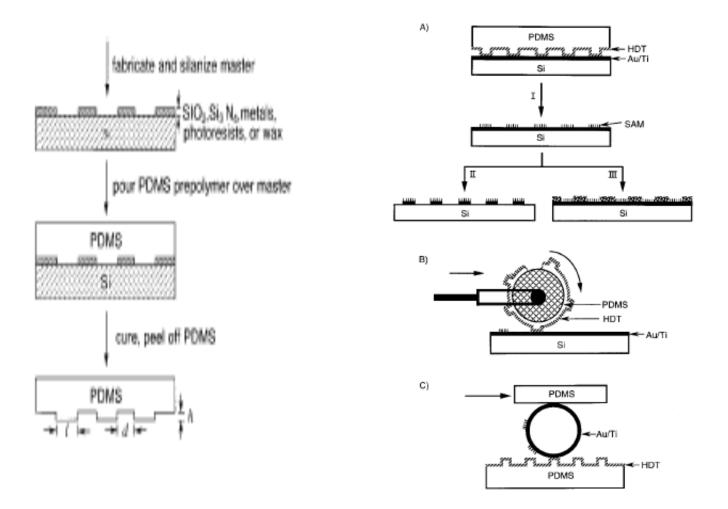
Micro-molding

Micro-fluid dynamics

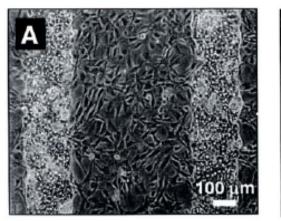
MEMpat

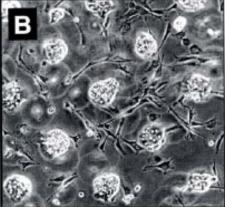
LIFT-OFF

Micro-Contact Printing



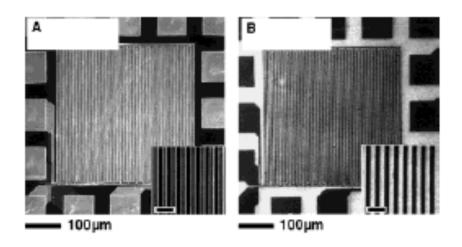
Results

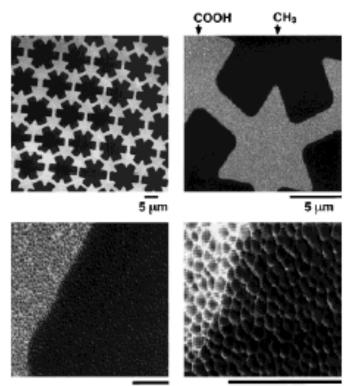






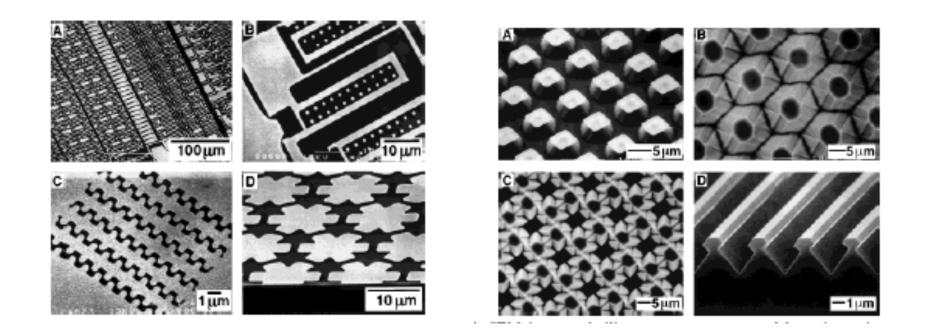
Results



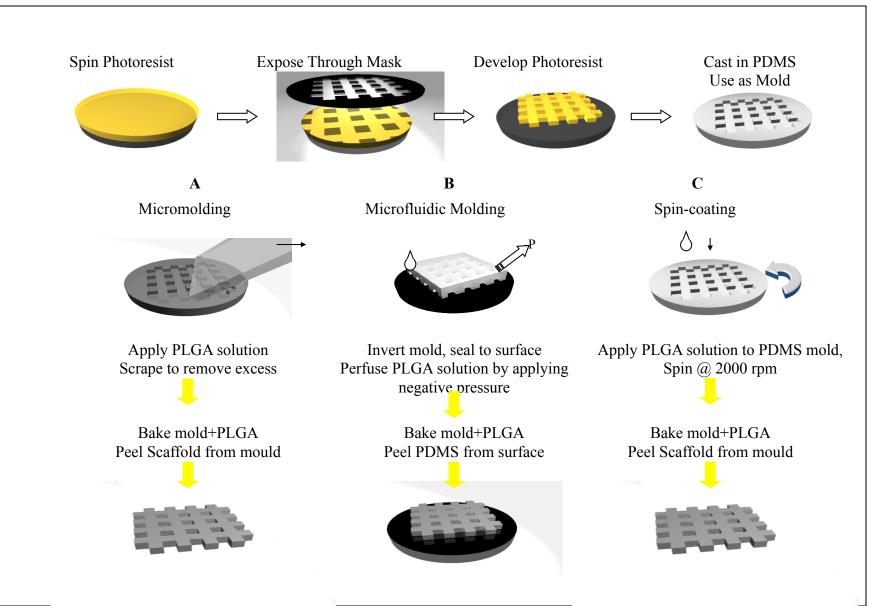


1 μ**m**

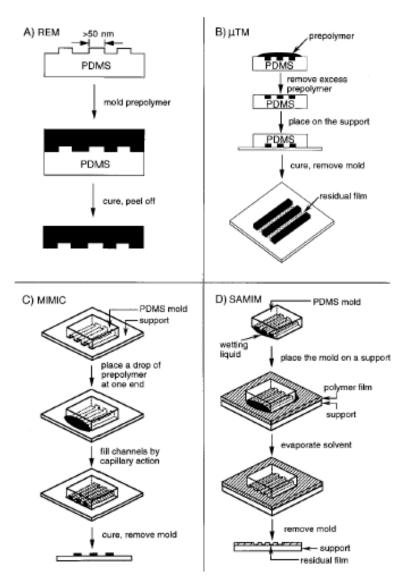
Risultati



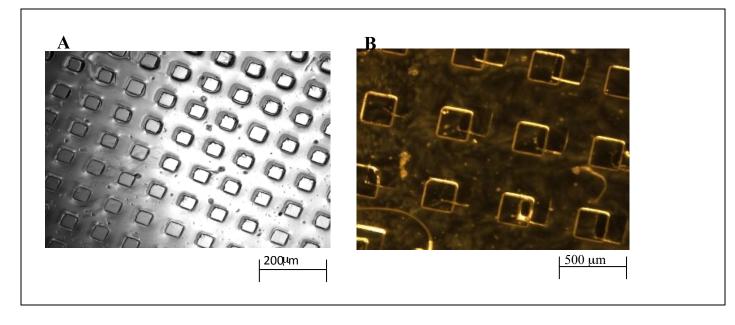
Micromolding

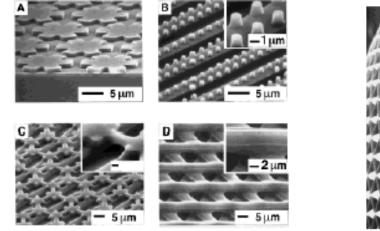


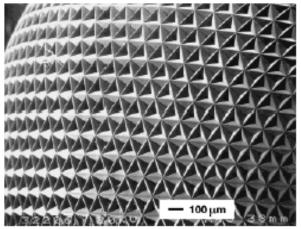
Micromolding



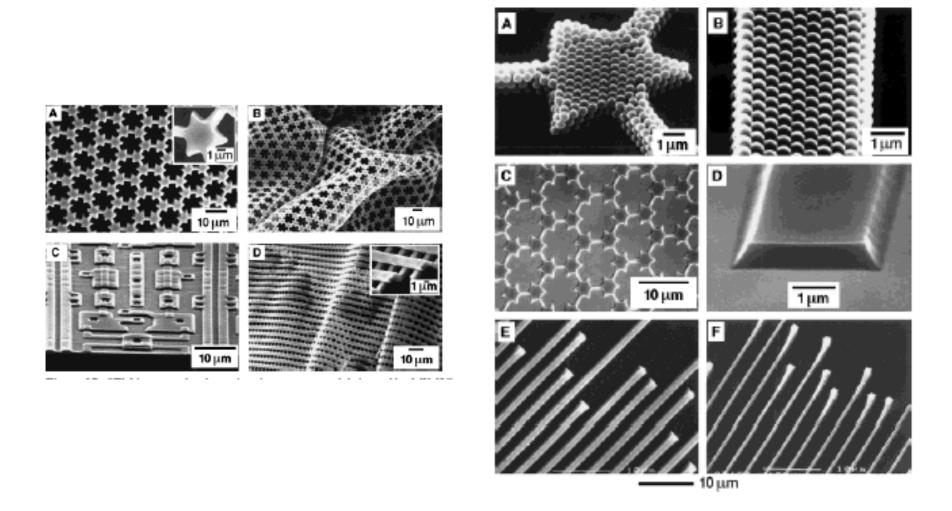
Risultati



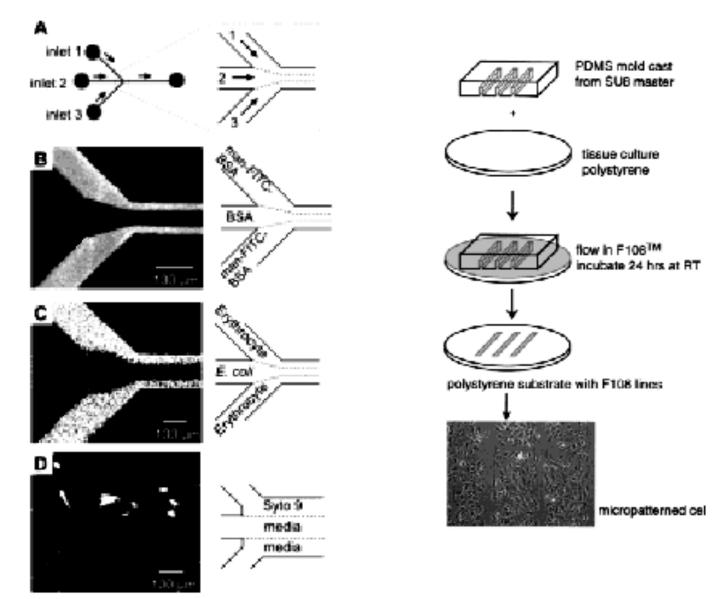




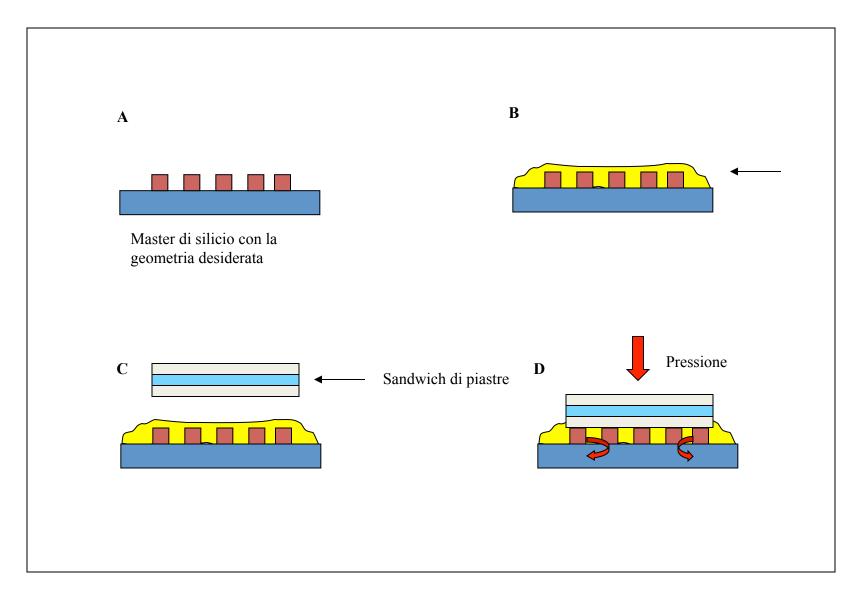
Results



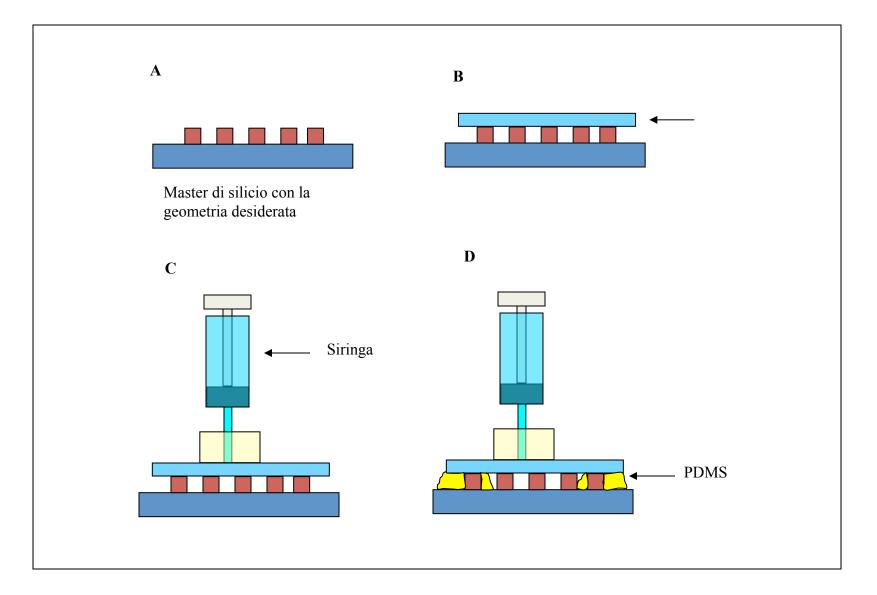
Micro Fluid Dynamic



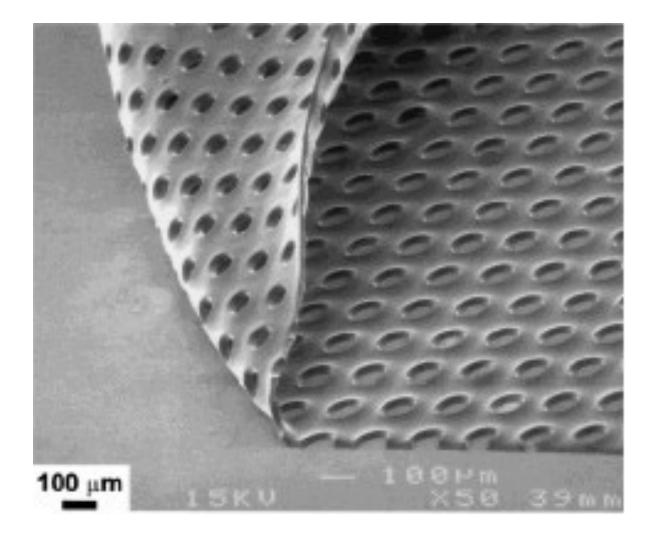
MEMpat



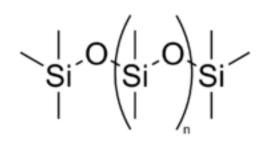
MEMpat



MEMpat



Polydimethylsilosane (PDMS)



The polydimethylsiloxane (PDMS) is obtained starting from dimethylchlorosilane [(CH3) 2SiHCl] which is a chemical compound produced by direct reaction between silicon and methyl chloride (CH3Cl). For subsequent hydrolysis of dimethyldichlorosilane cyclic and linear siloxanes are obtained, subsequently they are polymerised in order to produce silicone polymers. The PDMS polymer is formed by the sequence of the following monomer: CH3

- Si-O -

CH3

It is characterized by a remarkable resistance to temperature, to chemical attack, to oxidation, it is an excellent electrical insulating and resistant to aging; it is optically clean (transparent), it is biocompatible, inert, it is neither toxic nor flammable. This polymer also does not bind to either the glass, neither the metal nor the plastic during solidification, but retains greater grip on smooth surfaces once solidified.



Features

- colourless
- Boiling temperature> 100°C
- Realtive density 1.1
- Dynamic viscoity 3500 Centipoise
- Dielectric Constant at 100 Hz = 2.72
- Dielectric Constant at 100 kHz= 2.68
- Dielectric Strength = 500 volts per mil v/mil
- Heat Cure 10 Minutes @ 150 Deg C
- Heat Cure 20 Minutes @ 125 Deg C
- Heat Cure 35 Minutes @ 100 Deg C
- Hydrophobic
- Mix Ratio 10:1 Base to Catalyst 87-RC
- Room Temperature Cure Hours= 48 Hours
- Self Leveling
- Shelf Life= 720 Days
- Temperature Range -45 Deg C to 200 Deg C
- Thermal Conductivity= 0.27 Watts per meter K
- Volume Resistivity = 2.9e+014 ohm-centimeters
- Water Resistant
- Working Time > 90 Minutes
- Elastic modulus around MPa



Methods to modify surface chemistry of PDMS

PDMS is hydrophobic

Chemical and/or Phyisal treatment to increase its wettability

Physical Treatments

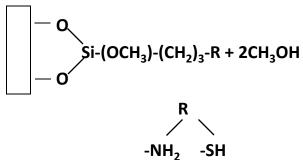
- **1.** Exposure to UV ray (λ = 350 nm)
- 2. Argon Plasma

Chemical Treatments

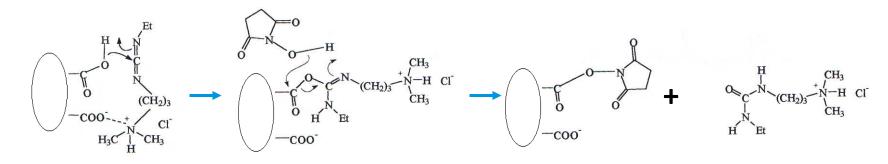
- 3. Dipping in Pyranha solution $(H_2SO_4:H_2O_2 30\% \text{ m/m} = 3:1 \text{ v/v})$
- 4. Dipping in H_2O_2 30% m/m in deionised water

Functionalisation of PDMS surface

- Derivatisation with polyfunctional silanes in a solution of toluene and deionsied water
- 3-aminopropyl-trimethoxysilane
 H₂N-(CH₂)₃₋Si-(OCH₃)₃
- 3-mercaptopropyl-trimethosilane
 HS-(CH₂)₃-Si-(OCH₃)₃



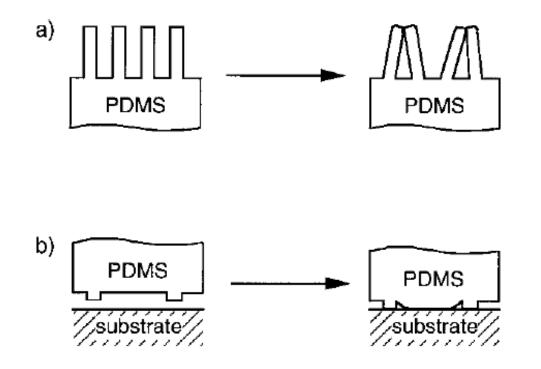
 Activation of reaction between carboxylic and nucelophylic gropuse di Nethyl-N'-(3-dimethylamminopropyl)-carbodiimmide (EDC) e N-hydroxysuccinimmide (NHS) in acquar



When a pressure is applied between the PDMS pattern and a substrate as in microcontact printing and the height of the silicon structures it is lower than the relative distance between the collapse of their structures.

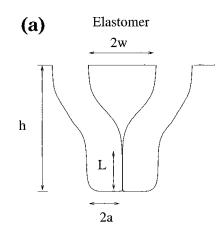
And if the aspect ratio is too high, the structures can be deformed and collapse.

They can adhere to each other if they are too close together.



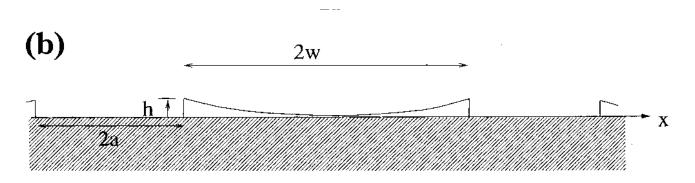
Delamarche et al. have shown that the 'aspect ratio (I / h) of structures made of PDMS must be between 0.2 and 2 to have molds free of defects.

Understanding the mechanisms that make the silicon structure stable and limitations in the design of the pattern is critical in soft-lithographic process. The main limitation is linked to the basal shear modulus that is less than 1 Mpa.



Biebuyck has shown experimentally that if h / 2a is too large the structures collapse and adhere to each other because of the pressure forces on the mold and of the capillary forces due to the fluid that bathes the surfaces.

However if the aspect ratio is too low, all the surfaces can be deformed due to the surface adhesion forces.



These phenomena are mainly due to the surface adhesion forces between the substrate adhesion and silicon structures. If we consider a mold PDMS ideal with regular and well straight topologically structures when these adhere to the substrate surface tensions in place because of the low shear modulus of the silicon will begin to deform, by varying the adhesion surface area and therefore the pattern key thing to consider when having structures with submicron resolution.

To reduce this problem you can increase the siliconeelastic module incorporating particles or increasing the cross-linker but this alters the chemical and physical characteristics of the material that may not adhere as well to master. Furthermore, the increase of the rigidity of the mold leads to less surface area to concentrate stress in the areas that during the manufacturing process may then break or come to a plastic deformation.

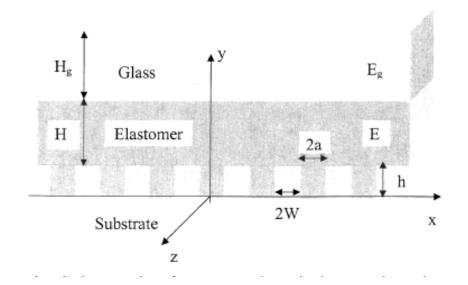
We analyze the problem and its possible solutions, using punches to a structure with a rectangular section.

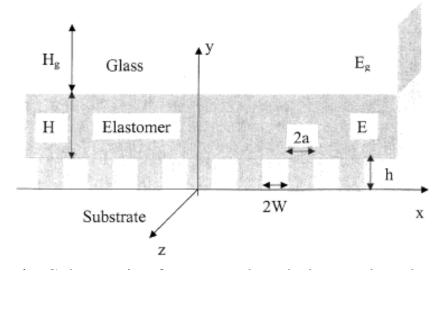
- h= Pillar Height
- 2a= Pillar width
- D= Mold lateral size
- H= Mold Thickness

Hypotheses:

 $H/D \ll 1 \qquad h/H \ll 1$

 $a/H \ll 1$ $w/H \ll 1$





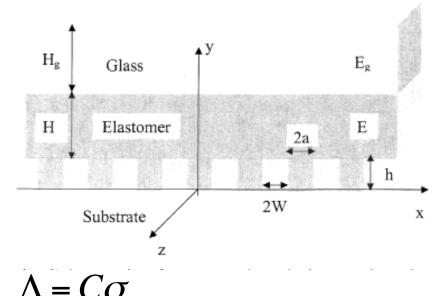
The number of pillars along x axis for length unit is :

$$N = \frac{1}{2(a+w)}$$

Suppose also that the applied loads do not vary along the z axis.

Often to work using a glass layer above the elastomeric mold which we assume Hg thickness.

The elastomer is assumed homogeneous and isotropic with Poisson coefficient equal to 0.5 and elastic modulus between 0.1 and 10 MPa



Initially, suppose that the pillars are detached from the substrate and then are pressed by a Δ tract that induces a compressive load σ , then the agent stress on the single punch is equal to:

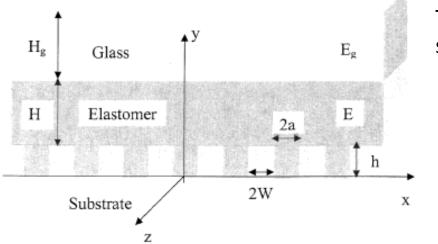
$$P = \frac{\sigma}{N} = 2(a+w)\sigma$$

 $\Delta = CO$

$$C = \frac{(1+\nu)(1-2\nu)H}{E(1-\nu)}$$

Since glass is stiffer than elastomer can we neglect the glass deformation in the x-y plane that would be equal to:

$$v_{vetro} \frac{\sigma}{E_{vetro}} < v_{vetro} \frac{E}{E_{vetro}} \cong 0$$



Then the silicone layer in the x-y plane is subjected to a state of biaxial stress

$$\sigma_{XX} = \sigma_{yy} = \frac{v\sigma}{(1-v)} \cong \sigma$$

So the silicone is subjected to pure compression except the edges that we neglect. On this basis the deformation undergone by the single pillar per unit length is:

$$\varepsilon = \frac{P}{E} = \frac{2(a+w)\sigma}{E}$$

(b) h ↓ 2w Aspect ratio (h/a)<<1 w ≅ a h/w<<1

When anexternal loadis appllied the maximum deformation which can have is equal to h (the pillar height) in the z direction but since the material is isotropic and homogeneous we will also lateral deformation. Therefore it is necessary to determine the contact force that is the upper limit of force before the mold begins to deform. Solving the system of forces the critical pressure is obtained and it is equal to:

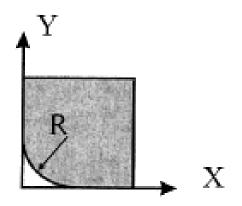
$$P_{\rm c} \approx \frac{1.36\pi^2 E^* a^3}{h^2}$$

From this one it is possible to derive the maximum critical height achievable with g weight per unit length. πd^4

$$I = \frac{\pi a}{64}$$
$$q = \rho g \pi \frac{d^2}{4}$$

$$h_{\rm c} = (7.837 E I/q)^{1/3}$$

For not having distortions we must have that the pillars are in contact with the substrate but still have not undergone deformations. But when the elastomer is in contact with the substrate the radius of curvature of the pillar varies due to the surface tension γ that so far we have not considered.



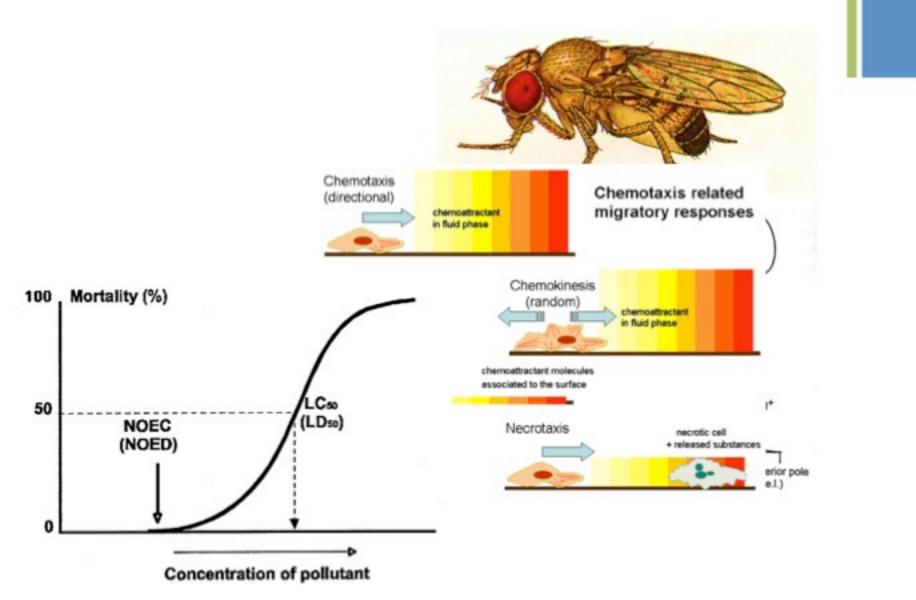
The pressure at the corners is therefore proportional to the surface tension $P{\approx}\gamma$ / r

and

r≈γ /

and generally it is seen that for the γ / And silicon is about 0.05 micrometers

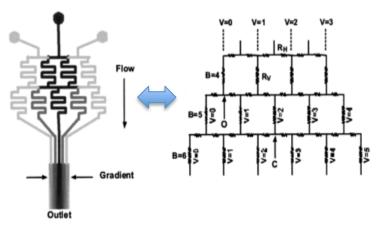
Importance of nonlinear concentration gradients



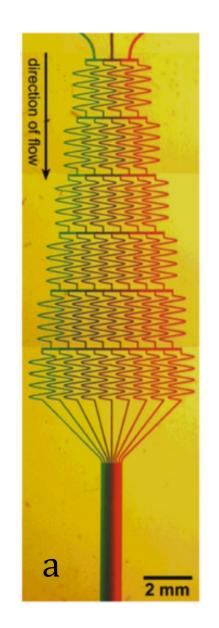
Gradient maker

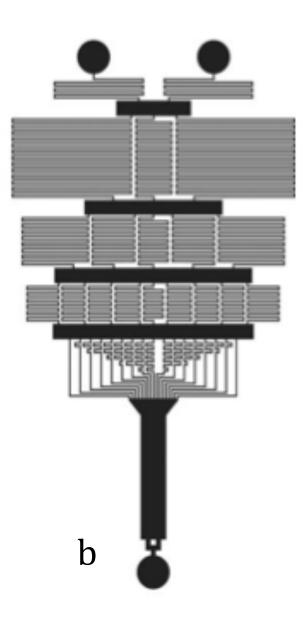
Necessary condition: Re << 1

The hydraulic circuit can be reduced in an electrical equivalent.

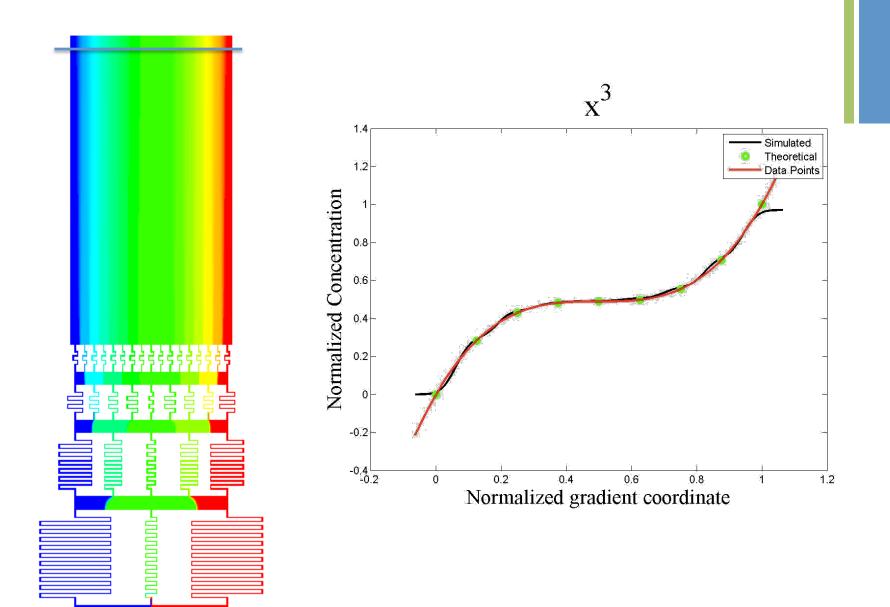


- a) S. K. W. Dertinger et al. *Analytical Chemistry*, 2001.
- b) K. Campbell etal., *Lab on a Chip*, 2007.





Simulated concentration pattern

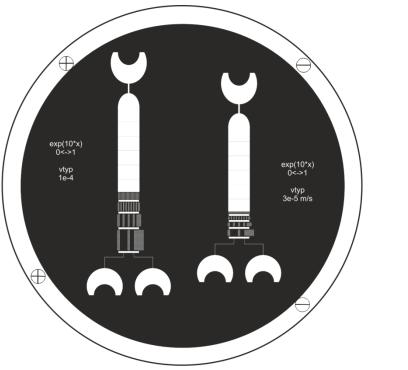


Realisation of the device



+ Realisation of the device

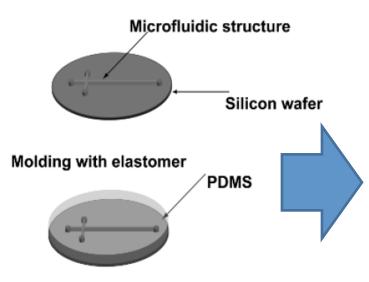
Silicon Wafer with SU-8 structure

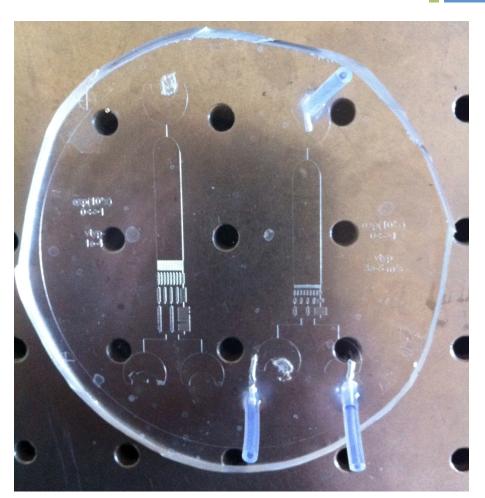




+ Realisation of the device

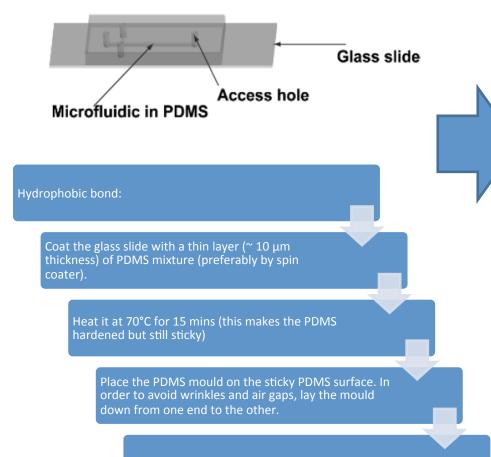
Master mold with microfluidic in resist

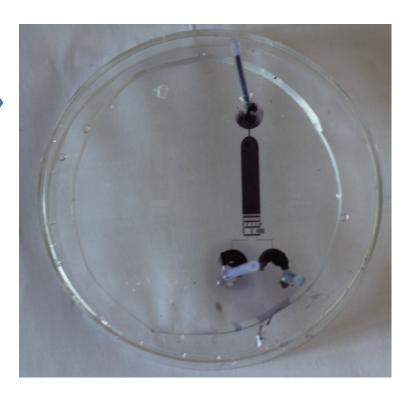




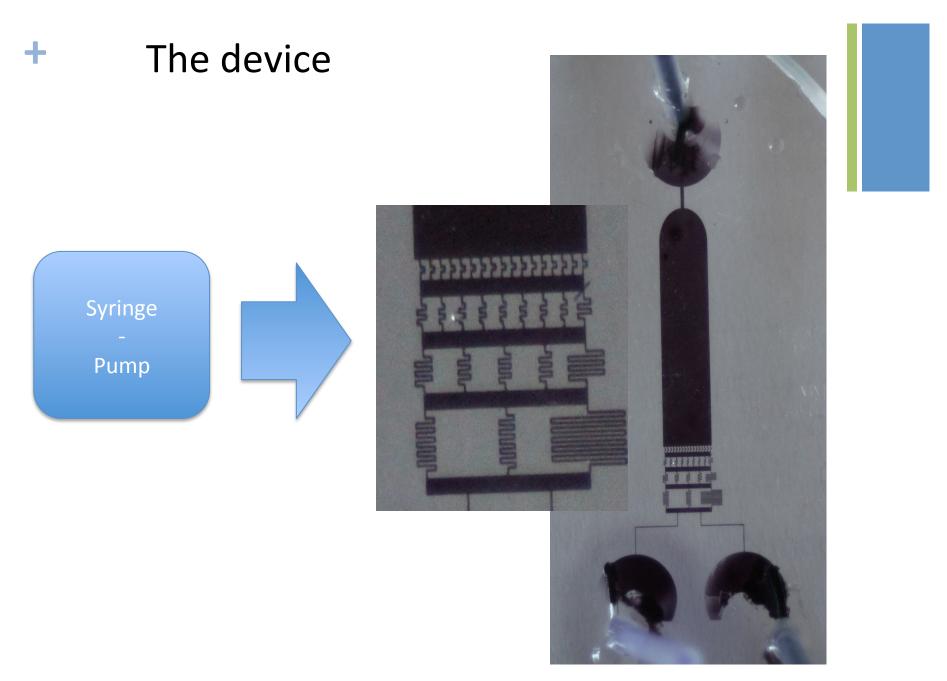
+ Gluing of the device

Peel elastomer, cut out, punch access hole and bond

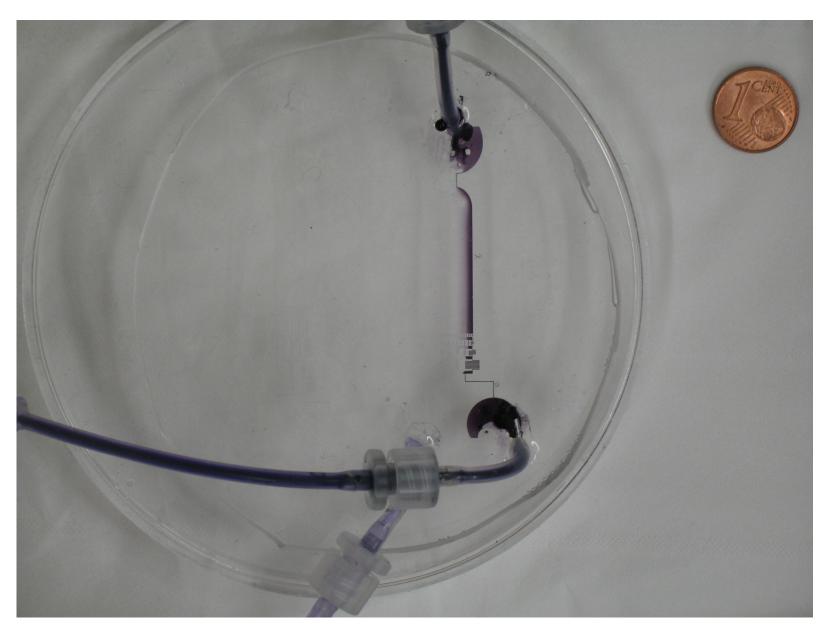




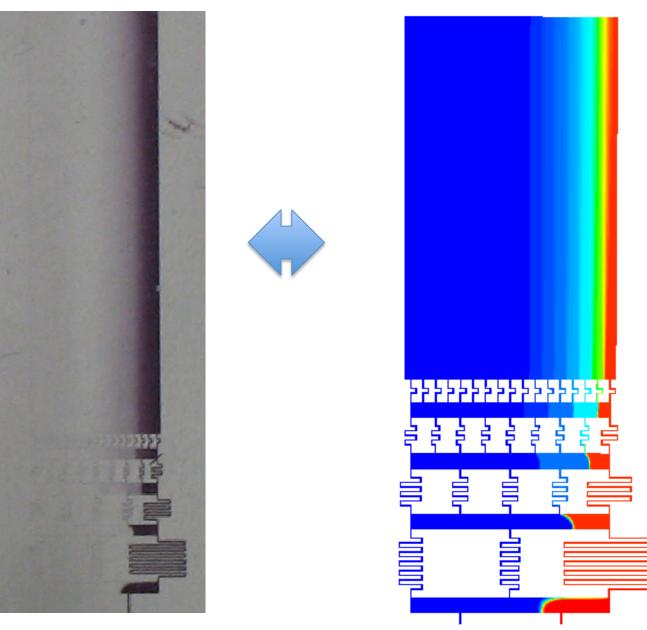
Heat it for at least 1 h at 70°C.



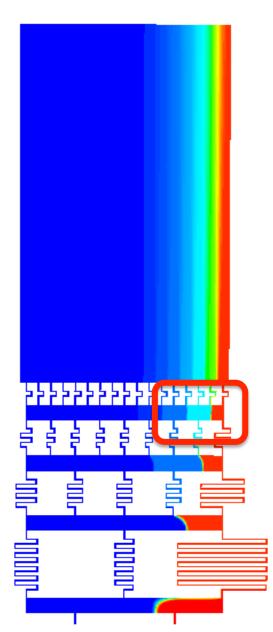


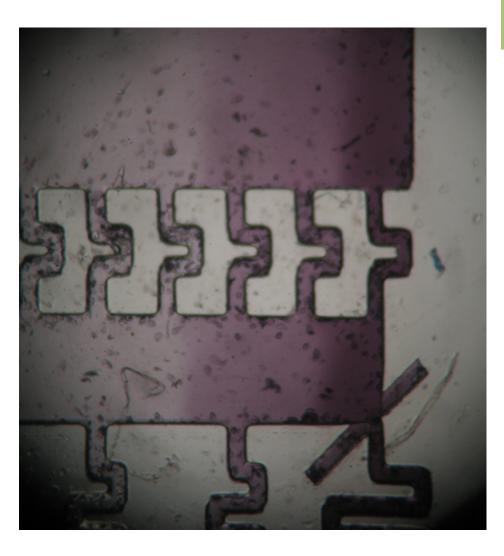


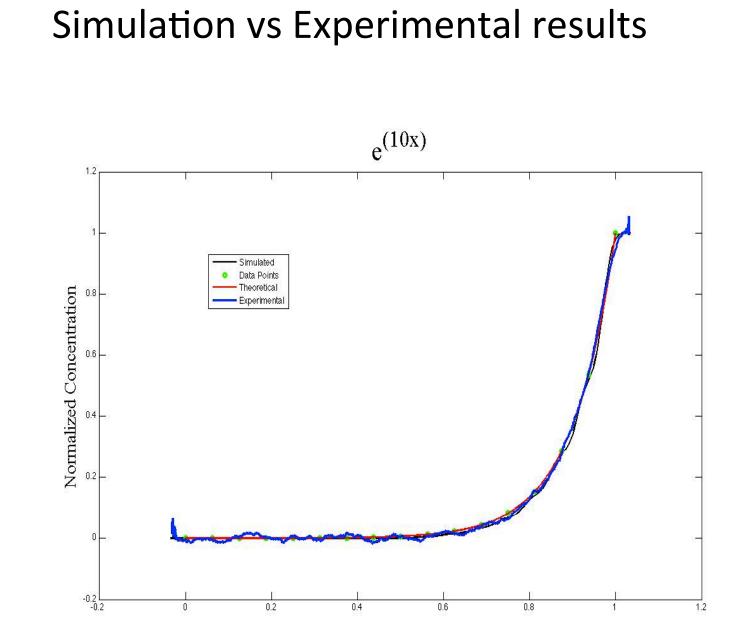
Simulation vs Experimental results



Simulation vs Experimental results







Normalized chamber length

+